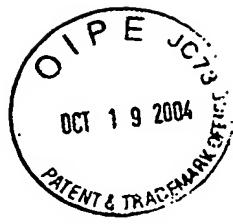


Form PTO 1449 (Modified)		U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE		ATTY DOCKET NO. 248520US2S		SERIAL NO. New Application	
LIST OF REFERENCES CITED BY APPLICANT		APPLICANT Yoshiaki FUKUZUMI					
		FILING DATE Herewith		GROUP			
U.S. PATENT DOCUMENTS							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
<i>W</i>	AA	6,005,800	12/21/99	Roger Hilsen KOCH, et al.	<i>W</i>	<i>W</i>	
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						
	AL						
	AM						
	AN						
FOREIGN PATENT DOCUMENTS							
		DOCUMENT NUMBER	DATE	COUNTRY	TRANSLATION		
	AO				YES	NO	
	AP						
	AQ						
	AR						
	AS						
	AT						
	AU						
	AV						
OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, etc.)							
<i>W</i>	AW	Roy SCHEUERLEIN, et al., "A 10ns Read and Write Non-Volatile Memory Array Using a Magnetic Tunnel Junction and FET Switch in each Cell", DIGEST OF TECHNICAL PAPERS, IEEE International Solid-State Circuits Conference, SESSION 7 / TD: EMERGING MEMORY & DEVICE TECHNOLOGIES, February 8, 2000, pgs. 128-129					
<i>W</i>	AX	Masashige SATO, et al., "Spin-Valve-Like Properties of Ferrromagnetic Tunnel Junctions", JPN. J. APPL. PHYS., Vol. 36 Part 2, No. 2B, February 15, 1997, pgs. L200-L201					
	AY						
	AZ	<input type="checkbox"/> Additional References sheet(s) attached					
Examiner <i>M. Johnson</i>				Date Considered <i>5-26-05</i>			
*Examiner: Initial if reference is considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.							



LIST OF RELATED CASES

<u>Docket Number</u>	<u>Serial or Patent Number</u>	<u>Filing or Issue Date</u>	<u>Inventor/ Applicant</u>
248520US2S*	10/771,548	02/05/04	FUKUZUMI
256211US2S	10/895,074	07/21/04	FUKUZUMI et al.

rgm ✓ M 8-26-05



LIST OF RELATED CASES

<u>Docket Number</u>	<u>Serial or Patent Number</u>	<u>Filing or Issue Date</u>	<u>Patent Appl. Publication No.</u>	<u>Inventor/Applicant</u>
248520US2S*	10/771,548	02/05/04		FUKUZUMI
258367US2S	10/933,247	09/03/04		IWATA, et al.

MJM ✓ M 5-26-05

*Present Application; listed for information

EHK/sch

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